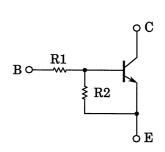
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1501,RN1502,RN1503 RN1504,RN1505,RN1506

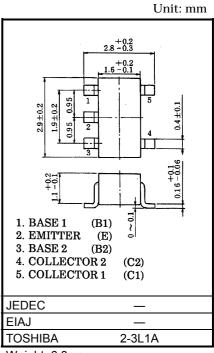
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SMV (super mini type with 5 leads)With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2501~RN2506

### **Equivalent Circuit and Bias Resister Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN1501	4.7	4.7
RN1502	10	10
RN1503	22	22
RN1504	47	47
RN1505	2.2	47
RN1506	4.7	47

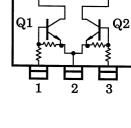


Weight: 6.8mg

### **Equivalent Circuit (Top View)**

## Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1501~1506	V <sub>CBO</sub>	50	V	
Collector-emitter voltage	KN1301*1300	V <sub>CEO</sub>	50	V	
Emitter-base voltage	RN1501~1504	V <sub>EBO</sub>	10	V	
	RN1505, 1506	VEBO	5		
Collector current		I <sub>C</sub>	100	mA	
Collector power dissipation	RN1501~1506	P <sub>C</sub> *	300	mW	
Junction temperature	KN1301*1300	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	
* Total rating	ı	_		Į.	



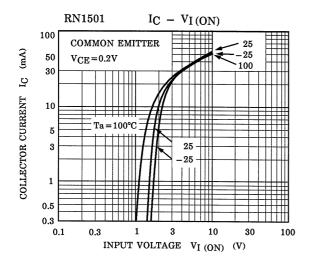
<sup>\*</sup> Total rating

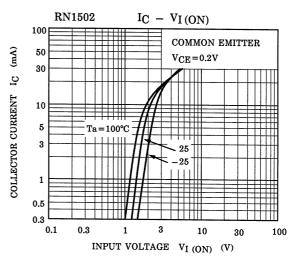


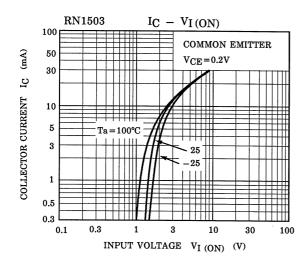
# Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

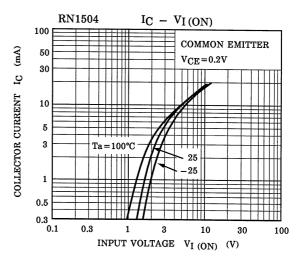
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off	RN1501~1506	I <sub>CBO</sub>		V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	n 1
current	KIN 1501~1500	I <sub>CEO</sub>		V <sub>CE</sub> = 50V, I <sub>B</sub> = 0		_	500	nA
	RN1501			V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	mA
Emitter cut-off current	RN1502	IEBO	_		0.38	_	0.71	
	RN1503				0.17	_	0.33	
	RN1504				0.082	_	0.15	
	RN1505			V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1506				0.074	_	0.138	
	RN1501				30	_	_	
	RN1502				50	_	_	
	RN1503				70	_	_	
DC current gain	RN1504	h <sub>FE</sub>	_	$V_{CE}$ = 5V, $I_C$ = 10mA	80	_	_	
	RN1505				80	_	_	
	RN1506				80	_	_	
Collector-emitter saturation voltage	RN1501~1506	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
-	RN1501	V <sub>I (ON)</sub> –			1.1	_	2.0	V
	RN1502				1.2	_	2.4	
	RN1503				1.3	_	3.0	
Input voltage (ON)	RN1504		_	V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.5	_	5.0	
	RN1505				0.6	_	1.1	
	RN1506				0.7	_	1.3	
	RN1501~1504	V <sub>I (OFF)</sub> —		V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	
Input voltage (OFF)	RN1505, 1506				0.5	_	0.8	V
Transition frequency	RN1501~1506	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector Output capacitance	RN1501~1506	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1501				3.29	4.7	6.11	
	RN1502	R1 —			7	10	13	1:0
	RN1503				15.4	22	28.6	
	RN1504			32.9	47	61.1	kΩ	
	RN1505			1.54	2.2	2.86		
	RN1506			3.29	4.7	6.11		
Resistor ratio	RN1501~1504		_		0.9	1.0	1.1	
	RN1505	R1/R2			0.0421	0.0468	0.0515	
	RN1506				0.09	0.1	0.11	

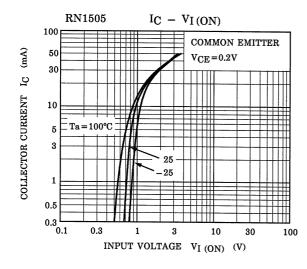
### (Q1, Q2 COMMON)

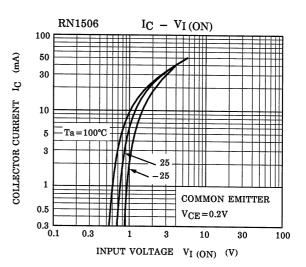




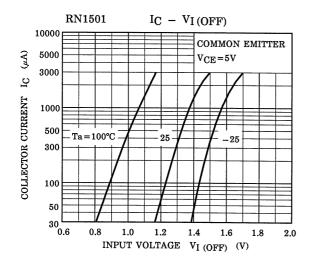


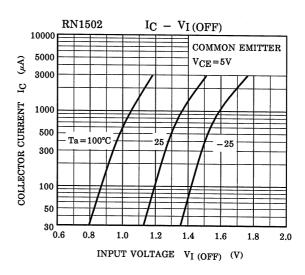


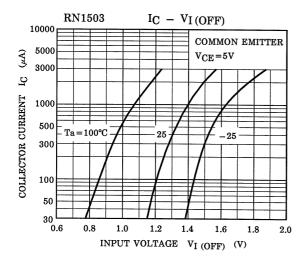


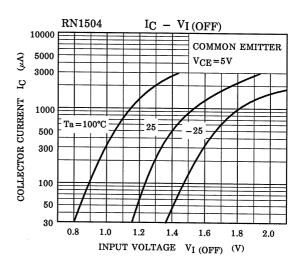


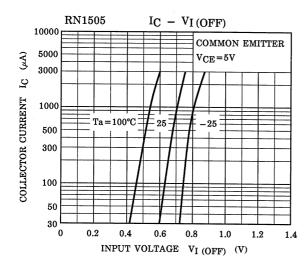
### (Q1, Q2 COMMON)

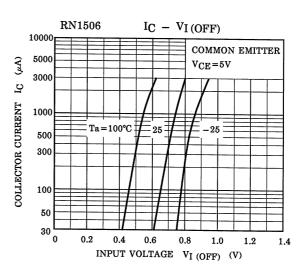




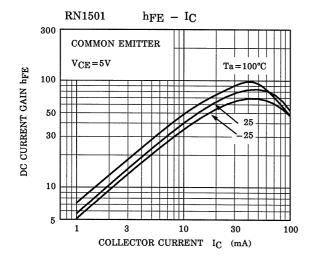


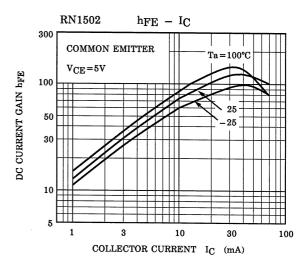


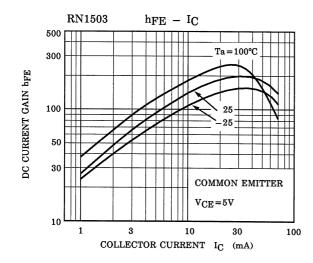


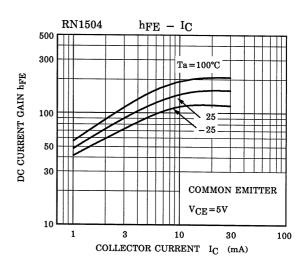


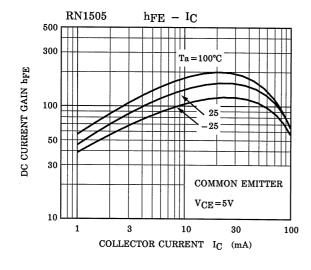
### (Q1, Q2 COMMON)

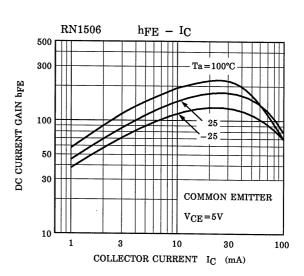












Type Name	Marking
RN1501	Type Name  X A
RN1502	Type Name  X B
RN1503	Type Name XC
RN1504	Type Name  X D
RN1505	Type Name  X E
RN1506	Type Name  X F

6 2001-06-07

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